

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
-100V	35mΩ@-10V	-25A
	45mΩ@-4.5V	

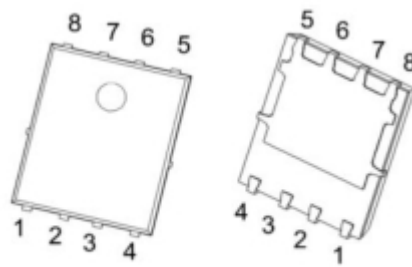
Feature

- V_{DS} -100V
- I_D -25A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) < 50 mohm
- Fast Switching

Application

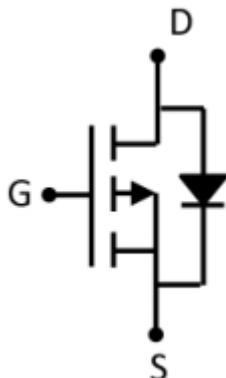
- Motor control
- Switching Regulators
- Isolated DC/DC convertor
- Alertor

Package

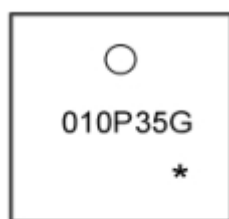


PDFNWB5X6-8L

Circuit diagram



Marking



010P35G =Device Code
***** =Month Code

Absolute maximum ratings

($T_a=25^{\circ}\text{C}$ unless otherwise noted)

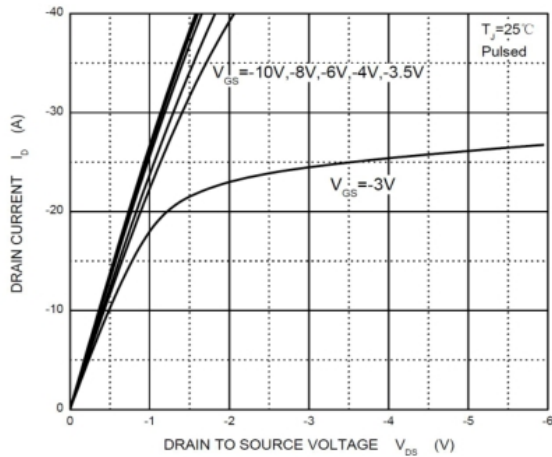
Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-100	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	-25	W
Drain Current – Pulsed ¹	I_{DM}	-100	A
Power Dissipation ($T_c=25^{\circ}\text{C}$)	P_D	100	W
Thermal Resistance Junction to Case	$R_{\theta JC}$	1.25	$^{\circ}\text{C}/\text{W}$
Storage Temperature Range	T_{STG}	-55~ +150	$^{\circ}\text{C}$
Operating Junction Temperature Range	T_J	-55~ +150	$^{\circ}\text{C}$

Electrical characteristics

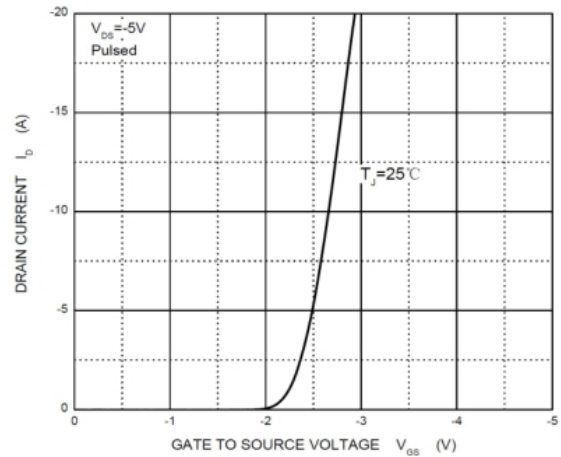
($T_A=25^{\circ}\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	BV_{DSS}	$V_{GS} = 0V, I_D = -250\mu A$	-100			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS} = -100V, V_{GS} = 0V$			-1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	μA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1	-1.6	-2.5	V
Static Drain-Source on-Resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -15A$		35	50	m Ω
		$V_{GS} = -4.5V, I_D = -10A$		45	65	
Dynamic characteristics ⁴						
Total Gate Charge	Q_g	$V_{GS} = -10V, V_{DS} = -20V, I_D = -12A$		96		nC
Gate-Source Charge	Q_{gS}			15		
Gate-Drain Charge	Q_{gd}			13		
Turn-On Delay Time	$T_{d(on)}$	$V_{GS} = -10V, V_{DD} = -20V, I_D = -20A, R_{GEN} = 3\Omega$		11		nS
Rise Time	T_r			17		
Turn-Off Delay Time	$T_{d(off)}$			37		
Fall Time	T_f			22		
Input Capacitance	C_{iss}	$V_{DS} = -20V, V_{GS} = 0V, f = 1MHz$		6300		pF
Output Capacitance	C_{oss}			220		
Reverse Transfer Capacitance	C_{rss}			55		
Drain-Source Diode Characteristics						
Continuous Source Current	I_S	$V_G = V_D = 0V$, Force Current			-30	A
Diode forward voltage	V_{SD}	$V_{GS} = 0V, I_S = -1A$			-1.2	V

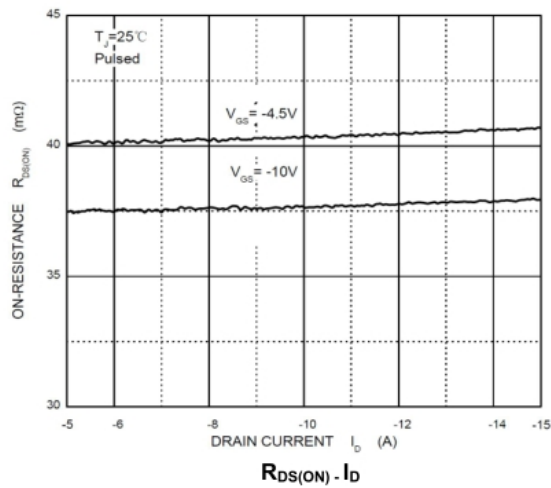
Typical Characteristics



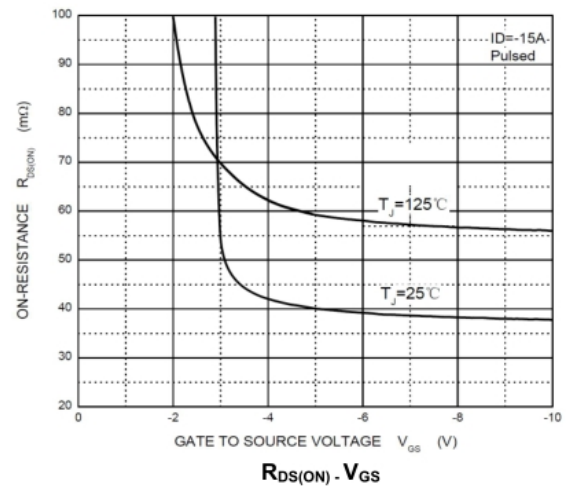
Output Characteristics



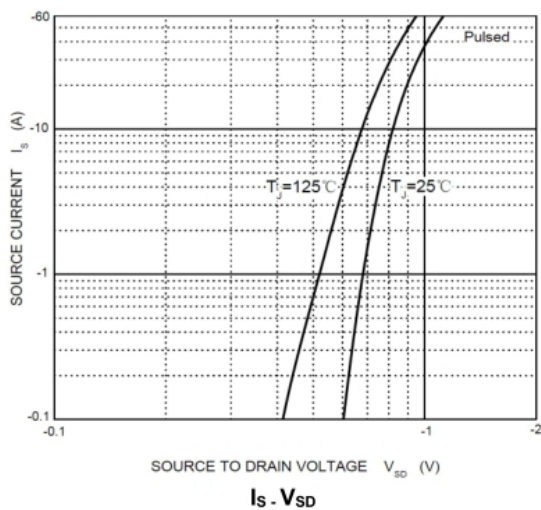
Transfer Characteristics



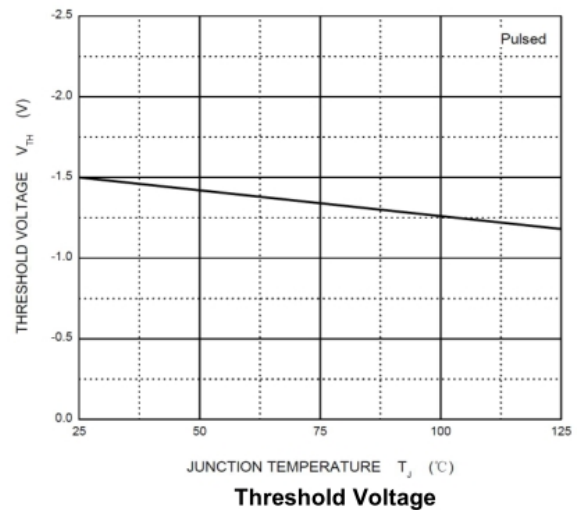
$R_{DS(ON)} - I_D$



$R_{DS(ON)} - V_{GS}$

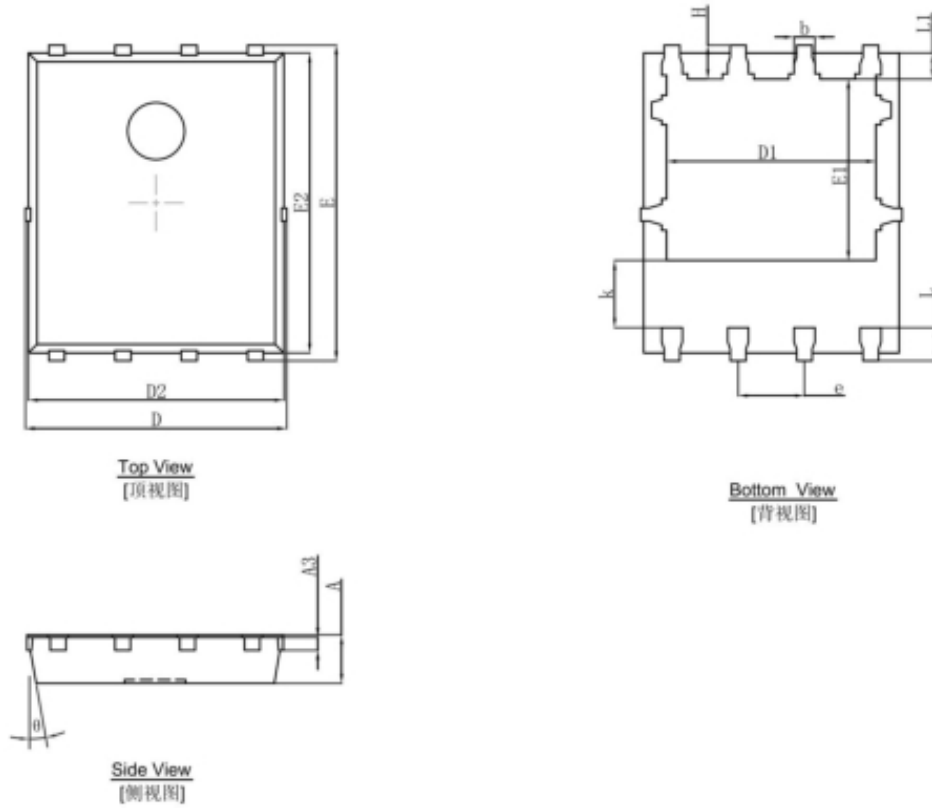


$I_S - V_{SD}$



Threshold Voltage

PDFNWB5X6-8L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.944	5.096	0.195	0.201
E	5.974	6.126	0.235	0.241
D1	3.910	4.110	0.154	0.162
E1	3.375	3.575	0.133	0.141
D2	4.824	4.976	0.190	0.196
E2	5.674	5.826	0.223	0.229
k	1.190	1.390	0.047	0.055
b	0.350	0.450	0.014	0.018
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°